



Driver Applications

Applications

· Suitable for use in switching of L load (motor drivers, printer hammer drivers, relay drivers).

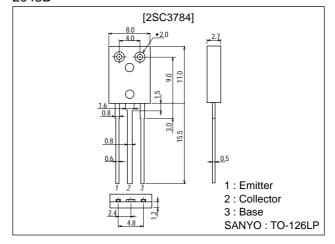
Features

- · High DC current gain.
- · Wide ASO.
- · On-chip Zener diode of 60±10V between collector and base.
- · Uniformity in collector-to-base breakdown voltage.
- · Large inductive load handling capability.

Package Dimensions

unit:mm

2043B



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		50*	V
Collector-to-Emitter Voltage	V _{CEO}		50*	V
Emitter-to-Base Voltage	V _{EBO}		6	V
Collector Current	IC		1.2	Α
Collector Current (Pulse)	I _{CP}		2.5	Α
Collector Dissipation	Do.		1.2	W
	PC	Tc=25°C	20	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

^{*:} On-chip Zener diode (60±10V)

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0			10	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =5V, I _C =0			10	mA
DC Current Gain	hFE	V _{CE} =5V, I _C =500mA	1000	4000		
Gain-Bandwidth Product	fT	V _{CE} =5V, I _C =500mA		180		MHz
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =500mA, I _B =2mA		1.0	1.5	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =500mA, I _B =2mA			2.0	V

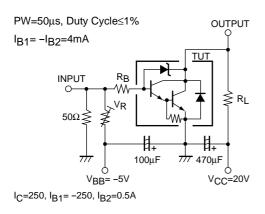
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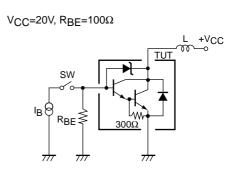
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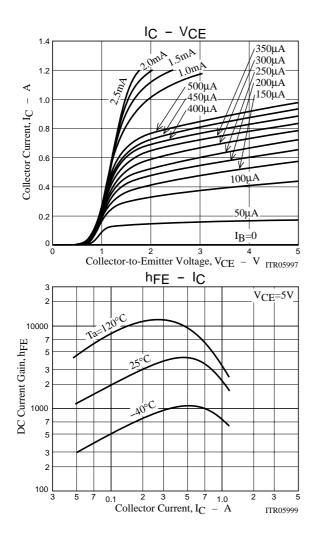
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	O'III
Inductive Load Handling Capability	Es/b	L=100mH, R_{BE} =100 Ω	15			mJ
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =100μA, I _E =0	50	60	70	V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	50	60	70	V
Turn-on Time	ton	See specified Test Circuit.		0.2		μs
Storage Time	t _{stg}	See specified Test Circuit.		2.2		μs
Fall Time	t _f	See specified Test Circuit.		0.4		μs

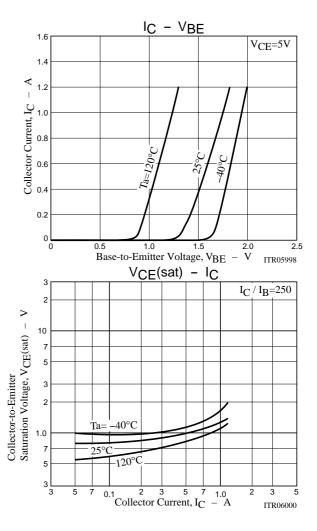
Switching Time Test Circuit

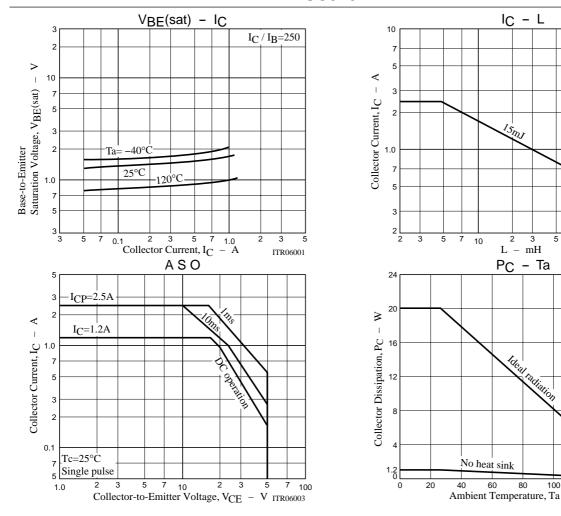


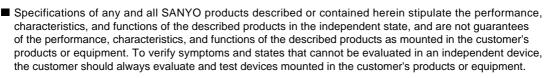
Es/b Test Circuit











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R_{BE}=100Ω

ITR06002

ITR06004

Tc=25°C